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Abstract for an Invited Paper
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Modeling and Ab initio Calculations of Thermal Transport in Si-Based Clathrates and Solar Perovskites¹
YUPING HE, University of California, Davis

We present calculations of the thermal transport coefficients of Si-based clathrates [1,2] and solar perovskites [3], as obtained from ab initio calculations and models, where all input parameters derived from first principles. We elucidated the physical mechanisms responsible for the measured low thermal conductivity in Si-based clathrates [1] and predicted their electronic properties and mobilities, which were later confirmed experimentally [2]. We also predicted that by appropriately tuning the carrier concentration, the thermoelectric figure of merit of Sn and Pb based perovskites may reach values ranging between 1 and 2, which could possibly be further increased by optimizing the lattice thermal conductivity through engineering perovskite superlattices.

[1] Y. He and G. Galli, *Nano. Lett.* 14, 2920 (2014).

[2] Y. He, F. Sui, S. M. Kauzlarich and G. Galli, *Energy Environ. Sci.* 7, 2386 (2014).

[3] Y. He and G. Galli, *Chem. Mat.* 26, 5394 (2014).

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